

The listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

~~filling an organic electroluminescence material into an evaporation cell preparing an evaporation cell filled with an organic electroluminescence material; and~~

~~heating evaporating the organic electroluminescence material in an inert gas atmosphere to form a pattern of a light emitting layer comprising the organic electroluminescence material [[on]] over a substrate comprising the organic electroluminescence material.~~

2. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

placing in a reaction chamber an evaporation cell containing an organic electroluminescence material and placing a shutter above an orifice of the evaporation cell;

~~heating evaporating the organic electroluminescence material in an inert gas atmosphere; and opening and closing the shutter to form a pattern of a light emitting layer comprising the organic electroluminescence material [[on]] over a substrate by opening and closing the shutter comprising the organic electroluminescence material.~~

3. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

~~filling an organic electroluminescence material into an evaporation cell preparing an evaporation cell filled with an organic electroluminescence material; and~~

~~heating evaporating the organic electroluminescence material in an inert gas atmosphere to selectively form a light emitting layer comprising the organic electroluminescence material selectively over a pixel electrode of the light-emitting device on a substrate comprising the organic electroluminescence material.~~

4. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

placing in a reaction chamber an evaporation cell containing an organic electroluminescence material and placing a shutter above an orifice of the evaporation cell;

~~heating evaporating the organic electroluminescence material in an inert gas atmosphere; and opening and closing the shutter to selectively form a light emitting layer comprising the organic electroluminescence material selectively over a pixel electrode of the light-emitting device by opening and closing the shutter on a substrate comprising the organic electroluminescence material.~~

5. (Original) A method of manufacturing a light-emitting device as claimed in claim 1, wherein more than one evaporation cell is provided.

6. (Original) A method of manufacturing a light-emitting device as claimed in claim 2, wherein more than one evaporation cell is provided.

7. (Original) A method of manufacturing a light-emitting device as claimed in claim 3, wherein more than one evaporation cell is provided.

8. (Original) A method of manufacturing a light-emitting device as claimed in claim 4, wherein more than one evaporation cell is provided.

9. (Original) A method of manufacturing a light-emitting device as claimed in claim 1, wherein the light-emitting device is a device selected from the group of: a personal computer, a video camera, a goggle-type display, a digital camera and cellular phone..

10. (Original) A method of manufacturing a light-emitting device as claimed in claim 2, wherein the light-emitting device is a device selected from the group of: a personal computer, a video camera, a goggle-type display, a digital camera and cellular phone.

11. (Original) A method of manufacturing a light-emitting device as claimed in claim 3, wherein the light-emitting device is a device selected from the group of: a personal computer, a video camera, a goggle-type display, a digital camera and cellular phone.

12. (Original) A method of manufacturing a light-emitting device as claimed in claim 4, wherein the light-emitting device is a device selected from the group of: a personal computer, a video camera, a goggle-type display, a digital camera and cellular phone.

13. (Original) A method of manufacturing a light-emitting device as claimed in claim 1, wherein the organic electroluminescence material is a small molecule material.

14. (Original) A method of manufacturing a light-emitting device as claimed in claim 2, wherein the organic electroluminescence material is a small molecule material.

15. (Original) A method of manufacturing a light-emitting device as claimed in claim 3, wherein the organic electroluminescence material is a small molecule material.

16. (Original) A method of manufacturing a light-emitting device as claimed in claim 4, wherein the organic electroluminescence material is a small molecule material.

17. (Original) A method of manufacturing a light-emitting device as claimed in claim 1, wherein the organic electroluminescence material is heated in an inert gas atmosphere at an atmospheric pressure.

18. (Original) A method of manufacturing a light-emitting device as claimed in claim 2, wherein the organic electroluminescence material is heated in an inert gas atmosphere at an atmospheric pressure.

19. (Original) A method of manufacturing a light-emitting device as claimed in claim 3, wherein the organic electroluminescence material is heated in an inert gas atmosphere at an atmospheric pressure.

20. (Original) A method of manufacturing a light-emitting device as claimed in claim 4, wherein the organic electroluminescence material is heated in an inert gas atmosphere at an atmospheric pressure.

21. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

~~filling an organic electroluminescence material into an evaporation cell preparing an evaporation cell filled with an organic electroluminescence material;~~

~~heating evaporating the organic electroluminescence material in an inert gas atmosphere to form a light emitting layer comprising the organic electroluminescence material selectively over a pixel electrode of the light emitting device on a substrate comprising the organic electroluminescence material; and~~

moving the evaporation cell and the substrate relative to each other ~~during the heating step~~.

22. (Currently amended) A method of manufacturing a light-emitting device, comprising the steps of:

placing in a reaction chamber an evaporation cell containing an organic electroluminescence material and placing a shutter above an orifice of the evaporation cell;

~~heating evaporating~~ the organic electroluminescence material in an inert gas atmosphere; ~~opening and closing the shutter to form a light emitting layer comprising the organic electroluminescence material selectively over a pixel electrode of the light-emitting device by opening and closing the shutter on a substrate comprising the organic electroluminescence material;~~ and

moving the evaporation cell and the substrate relative to each other ~~during the heating step~~.

23. (Currently Amended) A method of manufacturing a light-emitting device according to claim 21, wherein the evaporation cell is moved ~~during the heating step~~.

24. (Currently Amended) A method of manufacturing a light-emitting device according to claim 22, wherein the evaporation cell is moved ~~during the heating step~~.

25. (Previously Presented) A method of manufacturing a light-emitting device according to claim 1, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

26. (Previously Presented) A method of manufacturing a light-emitting device according to claim 2, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

27. (Previously Presented) A method of manufacturing a light-emitting device according to claim 3, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

28. (Previously Presented) A method of manufacturing a light-emitting device according to claim 4, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

29. (Previously Presented) A method of manufacturing a light-emitting device according to claim 21, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

30. (Previously Presented) A method of manufacturing a light-emitting device according to claim 22, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

31. (Previously Presented) A method of manufacturing a light-emitting device according to claim 2, wherein a diameter of the orifice is several tens to several hundreds μm .

32. (Previously Presented) A method of manufacturing a light-emitting device according to claim 4, wherein a diameter of the orifice is several tens to several hundreds μm .

33. (Previously Presented) A method of manufacturing a light-emitting device according to claim 22, wherein a diameter of the orifice is several tens to several hundreds μm .

34. (New) The method of claim 1 wherein said pattern is directly deposited from said evaporation cell.

35. (New) The method of claim 2 wherein said pattern is directly deposited from said evaporation cell.

36. (New) The method of claim 1 wherein said pattern is formed over said substrate without the use of a mask.

37. (New) The method of claim 2 wherein said pattern is formed over said substrate without the use of a mask.

38. (New) A method of manufacturing a light-emitting device, comprising the steps of:

preparing an evaporation cell filled with an organic electroluminescence material, said evaporation cell having an orifice like ejecting port adapted to directly deposit a pattern of a light-emitting layer comprising the organic electroluminescence material over a substrate; and

evaporating the organic electroluminescence material in an inert gas atmosphere to form the pattern of a light emitting layer comprising the organic electroluminescence material over the substrate.

39. (New) A method of manufacturing a light-emitting device according to claim 38, wherein the evaporation cell is moved.

40. (New) A method of manufacturing a light-emitting device according to claim 38, wherein the evaporation cell comprises a material selected from the group consisting of boron nitride, alumina and tungsten.

41. (New) A method of manufacturing a light-emitting device according to claim 38, wherein a diameter of the orifice is several tens to several hundreds μm .